

A Wide Range PLL Using Self-Healing Prescaler/VCO in CMOS

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Abstract:

A phase locked loop is widely employed in wireline and wireless communication systems. The design of frequency synthesizer, often implemented by a phase locked loop (PLL), is a challenging task for RF designers in terms of power dissipation. The variability and leakage current in nanoscale CMOS technology may degrade the circuit performances. To accommodate those issues in a wide range phase locked loop (PLL), a self-healing prescaler and a self-healing voltage controlled oscillator (VCO) are used. A CMOS fully programmable 1 MHz resolution divider for Zigbee and IEEE 802.15.4 applications is implemented based on pulse-swallow topology which uses the proposed ultra-low power divide by $32/33/47/48$ multimodulus prescaler. A self-healing divide by $2/3$ prescaler is the basic building block for designing of multimodulus prescaler. This proposed fully programmable multimodulus prescaler can consume an average power of $18.09\mu\text{W}$.

Index Terms:

Phase locked loop, Frequency synthesizer, Self-Healing prescaler, VCO, Leakage current, Multimodulus prescaler.

I. INTRODUCTION:

Complementary-metal-oxide-semiconductor (CMOS) [1] is a technology for constructing integrated circuits. CMOS technology is used for analog [1] highly integrated transceivers for many types of communications. Two important characteristics of CMOS devices are high noise immunity and low static power consumption.

A phase locked loop [4] is a control system that generates an output signal whose phase is related to the phase of an input signal. PLL is a feedback system that combines a voltage controlled oscillator (VCO) [4] and a phase comparator so connected that the oscillator maintains a constant phase angle relative to a reference signal. PLLs are used to generate a stable output high frequency signals from a fixed low frequency signal. When a CMOS technology approaches to a nanometer scale the non-idealities such as variability and leakage current, may significantly affect the circuit performances. The process variability leads to the large variations to degrade the device matching and performances. It may result in a few dies on a wafer to meet the target performance specifications.

The undesired leakage currents also degrade the accuracy and resolution of the circuits. A phase locked loop (PLL) is widely employed in wire-line and wireless communication systems. The poor device matching and leakage current [5], [7] vary the common-mode voltage of a ring based voltage-controlled oscillator (VCO) over wide frequency range. It may limit the oscillation frequency range of a VCO [6] and causes a VCO not to oscillate in a worst case. To realize a wide range PLL, the divider following a VCO should be operate between the highest and lowest frequencies.

There are many applications that require the synthesis of frequencies above 3GHz. However, this range is generally beyond the maximum frequency range that PLL devices can directly accept. By using an external prescaler [3], the range of PLL can be extended. When a PLL works at a higher frequency which the static circuits cannot operate, dynamic circuits are needed.

II. EXISTING CIRCUIT DESCRIPTION

A. Self-Healing Divide-by-4/5 Dual-Modulus Prescaler

Fig. 2(a) shows a conventional divide-by-4/5 dual-modulus prescaler using TSPC DFFs [3]. The undesired leakage current [2] may charge or discharge to alter the states of the nodes A, B, AND Qbar in this TSPC DFF.

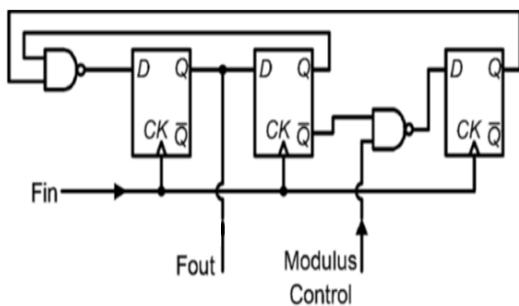


Fig.1. Conventional self-healing divide by 4/5 dual modulus prescaler.

The DFF is designed by using a method True Single Phase Clocking (TSPC) approach. TSPC is a dynamic CMOS approach to designing low power circuits. A TSPC prescaler must work over a wide frequency range to cover the process and temperature variations. For a TSPC prescaler, the undesired leakage currents may limit its frequency range or alter the original states of the floating nodes to have a malfunction.

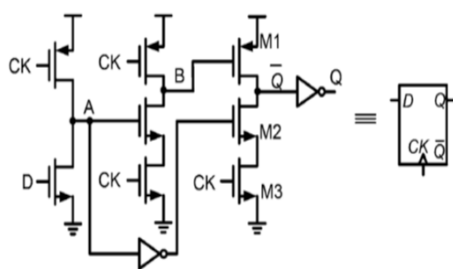


Fig. 1(a) internal circuit of TSPC DFF.

To detect and heal the above issues occurred at the nodes A and Qbar, the self-healing circuit is used. This self-healing circuit consists of a detector and three compensators. By using a self-healing circuit, the timing diagrams of a TPSC DFF with and without a malfunction are shown below.

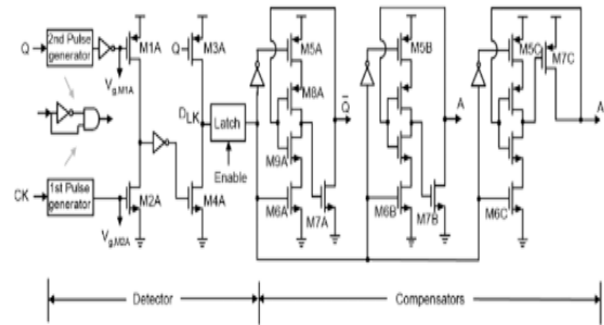


Fig. 1(b) self-healing circuit for prescaler.

B. Self-Healing VCO:

A self-healing VCO is realized by four gain stages, a bottom-level detector, and a current compensator. Fig. 2 shows a bottom-level detector, a current compensator, and a gain stage. The cross-coupled pair, M5 and M6, enhances the output swing of this VCO. The output common-mode voltage and the output swing of the VCO are altered by the leakage currents, the total tail currents and the resistance of M3 and M4. The bottom-level detector is shown in Fig. 2 and it detects the bottom-level of the VCO's output swing. A self-biased buffer enlarges the output of a VCO into a rail-to-rail swing. So, the output, Vbuf, of this self-biased buffer and Vout+ have the same polarity. When Vout+ goes high and Vbuf is high, the NOR gate will enable MB1 and disable MB2, respectively. The current of the transistor MB1 will charge the capacitor, CH, to increase VBL. The capacitor CH is used to track the bottom level of the VCO swing. The current compensators enables the tail currents when the bottom level is higher than the target swing voltage.

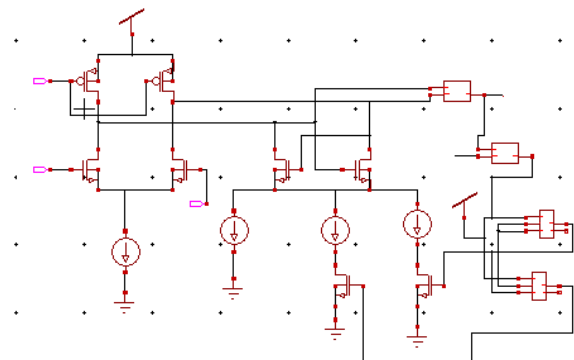


Fig. 2 gain stage of Voltage Controlled Oscillator.

For the current compensator a reference voltage V_{sw} represents the target bottom level of the VCO's swing and it is compared with V_{bl} , by a comparator. When the VCO's bottom level is smaller than the target one or the output common mode voltage of this VCO is high enough, V_{bl} is larger than V_{sw} . Then, the output of the comparator goes high and enables Q_1 . The current compensator enables the auxiliary tail current I_1 to lower the output common-mode voltage. Then, it reduces the VCO's bottom level to be lower than V_{sw} . If the above case is not true, Q_2 will be enabled and turn on the auxiliary tail current I_2 . It further lowers the VCO's bottom level.

C.Phase locked loop:

The PLL [8] is composed of a phase-frequency detector (PFD), a digital-controlled CP, a lock detector (LD), a time-to-digital converter (TDC) [8] with a 4-bit encoder, a self-healing VCO, a programmable divider, and a second-order passive loop filter. The programmable divider is composed of a 5-bit counter, a 3-bit swallow counter, a modulus control, and a self-healing divide-by-4/5 prescaler. The division ratio is from 4 to 131.

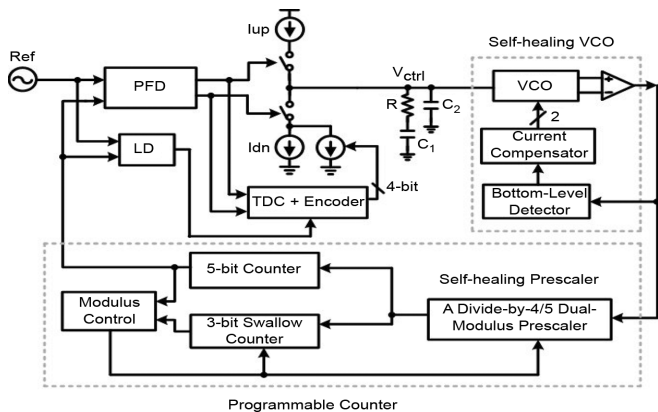


Fig. 3 The existing PLL.

D.Counter:

The programmable counter consists of a self-healing divide by 4/5 prescaler with fractional counter those are 5-bit counter and 3-bit swallow counter.

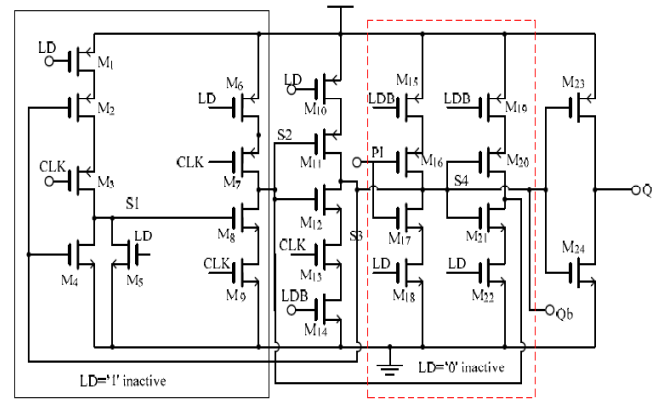


Fig. 4 Basic building block of programmable counter.

The basic cell is a CMOS circuit having LD, LDbar, CLK and PI signals as shown in fig. 4. These counters are used to get the division ratios from 4 to 131. The 5-bit p-counter consists of 5 basic cells and swallow counter having three basic cells.

Table 1 Operation of the basic cell:

Load(LD)	Programmable input(PI)	Output(Q)
0	0	CLK/2
0	1	CLK/2
1	0	0
1	1	1

When LD signal is low then the cell operates in divide by 2 mode otherwise output follows the programmable input. Once the programmable input (PI) of the each reloadable FF is loaded with a value and LD signal goes low, the P-counter begins to count down. Under this condition, the right hand side of the reloadable DFF as highlighted in Fig.4.4 is deactivated and transistor M_5 is turned-off such that the FF acts as a divide-by-2 circuit where node S_3 is complimentary of the divide-by-2 output. The FF remains in the divide-by-2 mode until the counter reaches the state "0000010". When $LD='1'$, the first two stages of the reloadable FF is deactivated and node S_1 always remains at logic '0' since the transistor M_5 is turned-on. Since node S_1 is at logic '0', node S_2 should be at logic '1'. However, node S_2 is overridden by the complimentary value of node S_4 . Under this condition ($LD='1'$), if the programmable input $PI='0'$, nodes S_4 and S_2 switch to logic '1' and '0' respectively. The value at node S_2 is latched to the output node Q on the next rising edge of the clock. Similarly, if $PI='1'$, the output Q switches to '1' on the clock rising edge. However when $LD='0'$, the bit-cell acts as a divide-by-2 circuit irrespective of the PI value.

The VCO operating range of the existing PLL is 60 to 1489MHz.s and the ref. frequency of this VCO is 15MHz. We can increase the operating frequencies of this VCO and then we get high frequencies by using prescaler. In order to get very wide ranges or the frequencies used for IEEE applications we go for multimodulus prescalers. The proposed multimodulus prescaler having division ratios of divide by 32/33/47/48. In this I used divide by 2/3 dual-modulus prescaler as a basic block.

III.PROPOSED MULTIMODULUS PRESCALER:

The proposed multimodulus prescaler [11] contains a divide by 2/3 dual modulus prescaler [11] followed by a MOD-16 counter and 7-bit programmable counter and a 5-bit swallow counter as shown in Fig. 5. This proposed multimodulus prescaler is designed in CMOS [1] 45nm technology to reduce the occupation of area and power consumption.

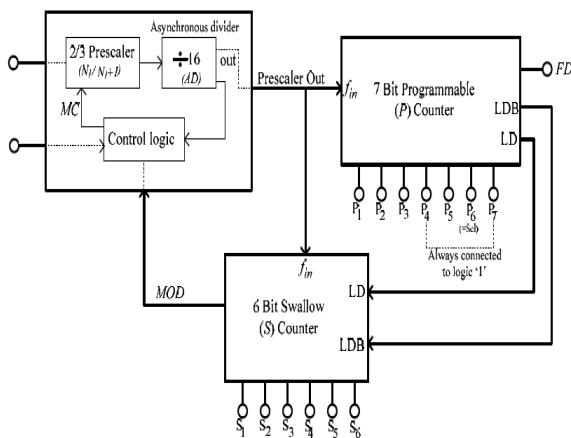


Fig. 5 Fully programmable multimodulus prescaler.

A CMOS fully programmable 1 MHz resolution divider for Zigbee and IEEE 802.15.4 applications is implemented based on pulse-swallow topology which uses the proposed ultra-low power 2/3 prescaler, low power 32/33/47/48 prescaler and a reloadable D flip-flop for the counters. A detailed design of wide-band 2/3 prescaler [11],[10],[9] based on dynamic logic is presented which is suitable for IEEE 802.11 a/b/g applications and also verified in the design of fully Programmable multimodulus prescaler as shown in Fig. 6.

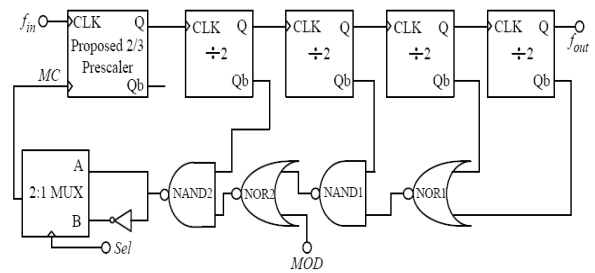


Fig. 6. Divide by 32/33/47/48 multimodulus prescaler.

A.MULTIMODULUS PRESCALER OPERATION:

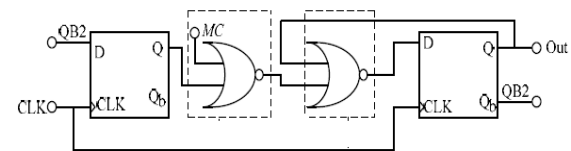


Fig. 6(a) Divide by 2/3 dual modulus prescaler

The divide by 2/3 dual modulus prescaler consists of two DFFs and two NOR gates. Fig. 6(a) shows the divide by 2/3 dual modulus prescaler using TSPC DFFs. The DFF is a TSPC DFF to reduce the power consumption and is works at high frequencies. If mode control signal is 0 then the dual modulus prescaler works as divide by 3 prescaler. If the mode control is 1 then the dual modulus prescaler acts as divide by 2 prescaler.

A fully programmable multimodulus prescaler operation is depends on sel signal. If sel is 0 and mod is 1 then the multimodulus prescaler acts as divide by 32 and mod is 0 then it acts as divide by 33 prescaler. If sel is 1 and mod is 0 then it acts as divide by 47 and mod is 1 then it acts as divide by 48 prescaler. The design can be progressed in CMOS 45nm technology.

IV.EXPERIMENTAL RESULTS:

When this PLL locks, the LD (Lock Detector) is enabled to turn on the TDC and an encoder. A 4-bit TDC digitizes this static phase error to reflect the amount of the current mismatching. Then, the digital code of this TDC is used to calibrate the charge pump. The CP calibration can be finished quickly due to this digital calibration. Once the calibration is completed, the digital code is fixed and the TDC is power-downed to save a power.

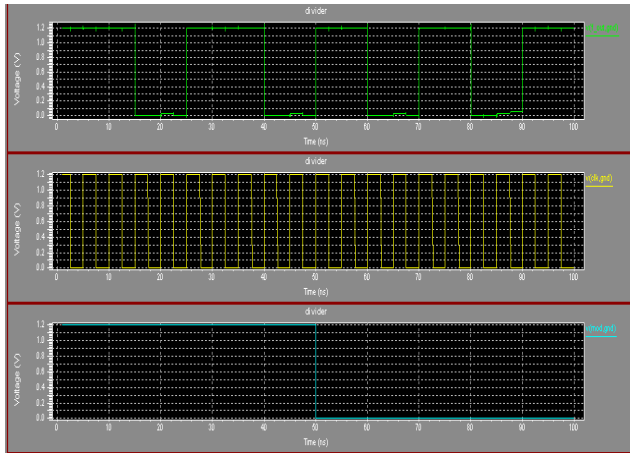


Fig. 7 simulation results of divide by 4/5 dual modulus prescaler.

The simulation results of the self-healing TSPC divide by 4/5 dual modulus prescaler is shown in Fig. 7. Which consume a power of $50\mu\text{W}$ when we simulate this in CMOS 65nm technology. The fully programmable counter can consume an average power of 0.11mW when we simulate this in CMOS 65nm technology.

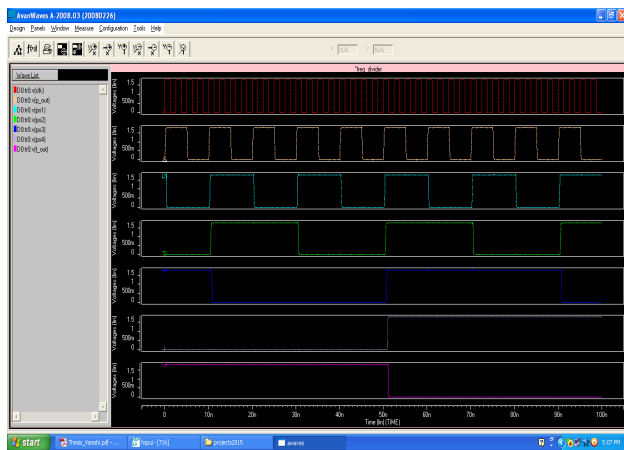


Fig. 8 The simulation result of fully programmable 4/5 divider.

The simulation result of programmable counter is shown in Fig. 8.

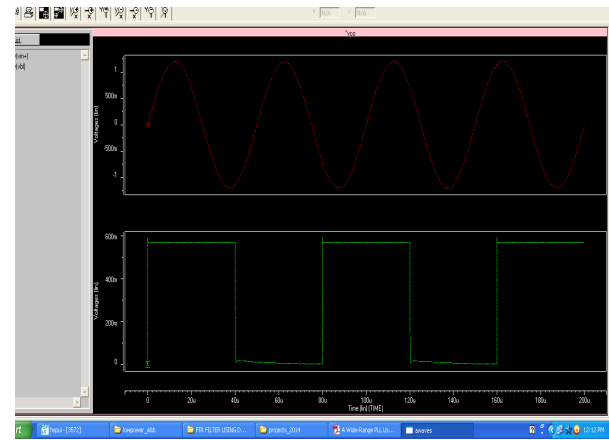


Fig. 9. The simulation result of VCO gain stage.

The VCO gain stage converts the analog signal to digital. Which is act as a CLK to the prescaler.

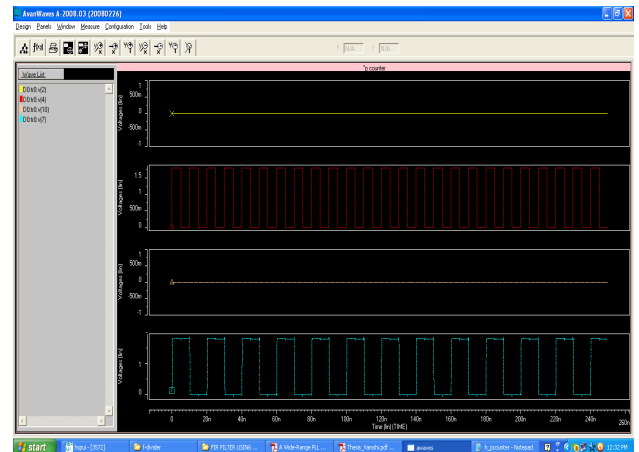


Fig. 10 Simulation result of counter basic cell when LD=0 and PI=0.

The non-idealities such as leakage current [2] and process variations can alter the VCO [6] gain in order to rectify those problems current compensators are used. As shown in Fig. 10 we know that when the LD=0 and PI is either 0 or 1 the output of the counter will be CLK divided by 2. Divided by 2 operation takes place here. These types of operations takes place in both programmable and swallow counters. In the proposed PLL [9] we have fully programmable multimodulus prescaler as shown in Fig. 5. In this we have a basic building block as TSPC divide by 2/3 dual modulus prescaler [10] as shown in Fig. 6. The simulation result of this divide by 2/3 prescaler is shown in Fig. 11. The average power consumed for this divide by 2/3 dual modulus prescaler [10] is $3.6\mu\text{W}$ when we simulate this in CMOS 45nm technology.

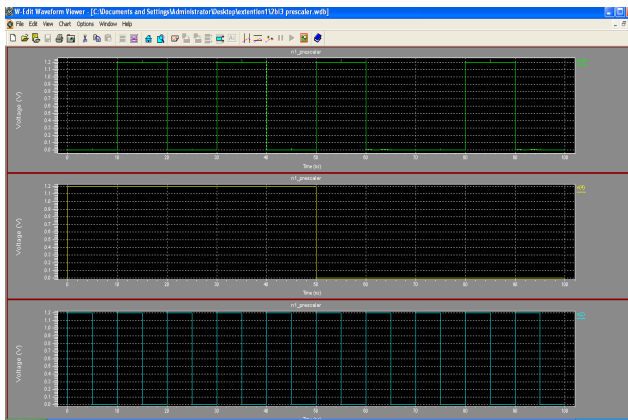


Fig. 11 Simulation result of divide by 2/3 TSPC dual modulus prescaler.

Fig. 12 shows the simulation result of the proposed fully programmable multimodulus prescaler. This multimodulus prescaler is used to extend the frequencies up to 6 GHz. Here the proposed multimodulus prescaler [11] is a CMOS fully programmable 1 MHz resolution divider for Zigbee and IEEE 802.15.4 applications is implemented based on pulse swallow topology. The range of P values among 74 to 77 then the P-counter can produce 2.4 GHz frequency which is used for Zigbee application. In this the multimodulus prescaler acts as divide by 32/33 dual modulus prescaler [11]. For IEEE 802.15.4 application the multimodulus prescaler can be operating in divide by 47/48 dual modulus prescaler [9], [10]. Here also the programmable counter will have 1MHz resolution signal can be applied to P-counter. P values ranging from 105 to 122. It can generate frequency ranges from 5.1 GHz to 5.82 GHz. The fully programmed multimodulus prescaler [9] can consume an average power of 18.09 μ W when we simulate this in CMOS 45nm technology. The simulation result is shown in Fig 12. We can extend the divide ratios by altering the P-values and S-values. Thus we can achieve more high frequencies from this low frequency PLL.

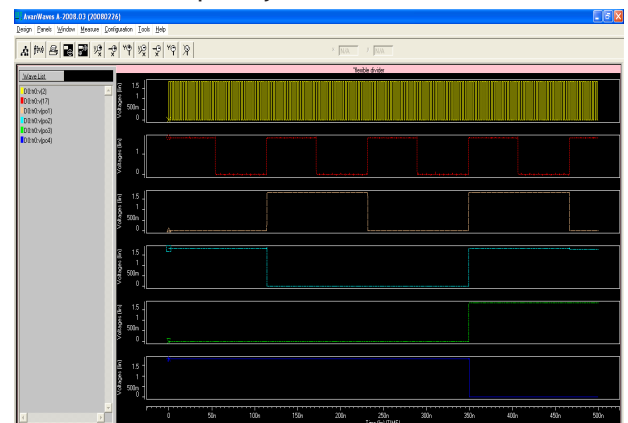


Fig. 12 Simulation result of fully programmed multimodulus prescaler.

V.CONCLUSION:

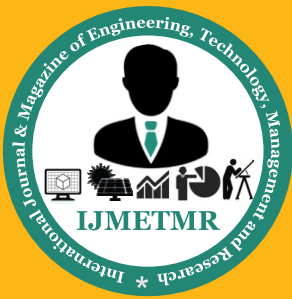
A wide-range PLL is designed in a 45-nm CMOS process. To deal with the process variability and leakage current in nanoscale CMOS process, a self-healing fully programmable multimodulus prescaler and a self-healing VCO are presented. The multimodulus prescaler can be able to operate accurately in a wide band from 1 MHz to 6 GHz. The core circuit occupies extremely tiny area and it consumes a less amount of power. Experimental results are given to demonstrate the feasibility.

VI.ACKNOWLEDGMENT:

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VII.REFERENCES:

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